

### SURFACE MOUNT RECTIFIERS

VOLTAGE RANGE: 50 --- 600 V  
CURRENT: 4.0 A

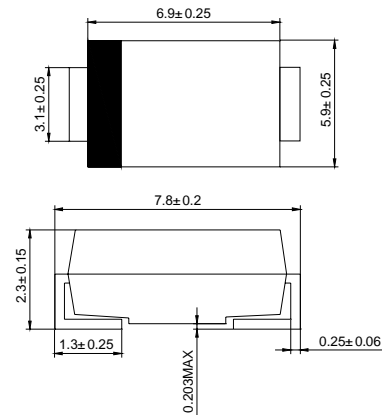
#### FEATURES

- ◇ Low cost
- ◇ Glass passivated chip junction
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

#### MECHANICAL DATA

- ◇ Case: JEDEC SMC, molded plastic
- ◇ Terminals: Solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.007 ounces, 0.21 grams
- ◇ Mounting position: Any

#### SMC(DO-214AB)



Dimensions in millimeters

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

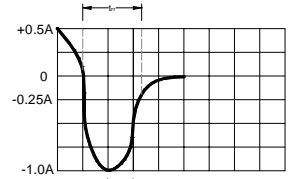
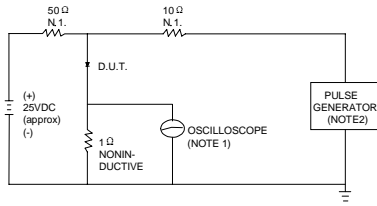
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		MURS 405	MURS 410	MURS 415	MURS 420	MURS 430	MURS 440	MURS 450	MURS 460	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current @ $T_A=75^\circ C$	$I_{F(AV)}$	4.0								A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	$I_{FSM}$	125.0								A
Maximum instantaneous forward voltage @ 4.0A	$V_F$	0.89				1.28				V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=125^\circ C$	$I_R$	10.0				100.0				$\mu A$
Maximum reverse recovery time (Note1)	$t_{rr}$	25				50				ns
Typical junction capacitance (Note2)	$C_J$	95								pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	20								$^\circ C/W$
Operating junction temperature range	$T_J$	- 55 ----- + 150								$^\circ C$
Storage temperature range	$T_{STG}$	- 55 ----- + 150								$^\circ C$

NOTE: 1. Measured with  $I_F=0.5A$ ,  $I_R=1A$ ,  $t_{rr}=0.25A$ .  
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.  
3. Thermal resistance from junction to ambient.

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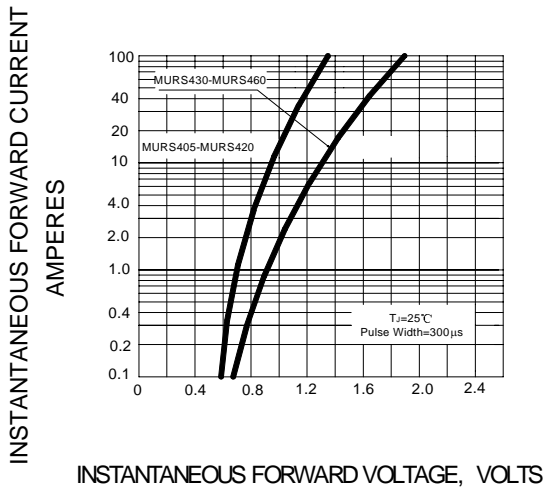
**FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



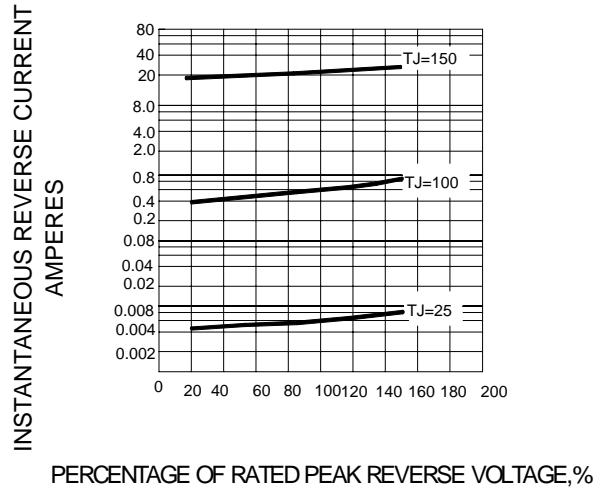
SET TIME BASE FOR 10/20 ns/cm

NOTES:1.RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ, 22pF.  
2.RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50 Ω.

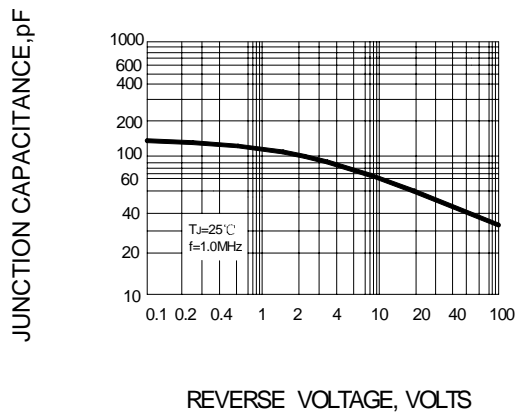
**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.3 – TYPICAL REVERSE CHARACTERISTIC**



**FIG.4 – TYPICAL JUNCTION CAPACITANCE**



**FIG.5 – FORWARD DERATING CURVE**

